National Semiconductor

March 1996

DM74AS873 Dual 4-Bit D-Type Transparent Latch with TRI-STATE® Outputs

General Description

These dual 4-bit registers feature totem-pole TRI-STATE outputs designed specifically for driving highly-capacitive or relatively low-impedance loads. The high-impedance state and increased high-logic-level drive provide these registers with the capability of being connected directly to and driving the bus lines in a bus-organized system without need for interface or pull-up components. They are particularly attractive for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

The eight latches of the AS873 are transparent D-type latches meaning that while the enable (G) is high the Q outputs will follow the data (D) inputs. When the enable is taken low the output will be latched at the level of the data that was set up.

A buffered output control input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state the outputs neither load nor drive the bus lines significantly.

The output control does not affect the internal operation of the latches. That is, the old data can be retained or new data can be entered even while the outputs are off.

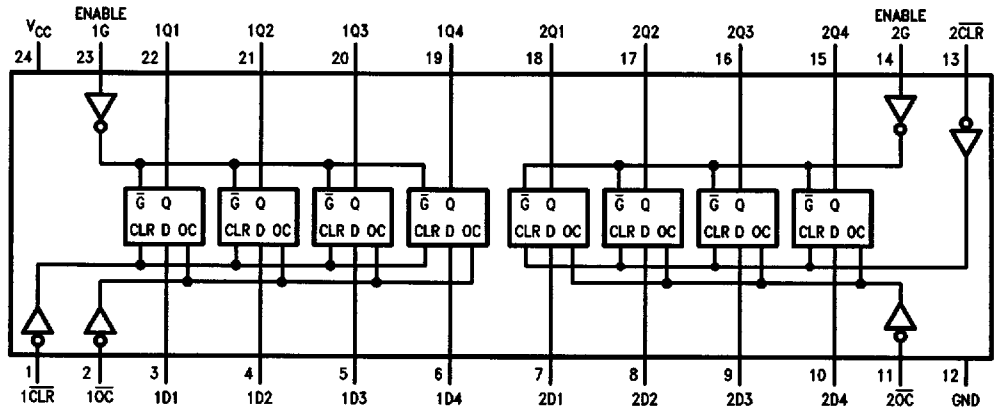
The pinout is arranged to ease printed circuit board layout. All data inputs are on one side of the package while all outputs are on the other side.

Features

- Switching specifications at 50 pF
- Switching specifications guaranteed over full temperature and V_{CC} range
- Advanced oxide-isolated, ion-implanted Schottky TTL process
- TRI-STATE buffer-type outputs drive bus lines directly
- Space Saving 300 Mil Wide Package
- Bus structured pinout

Connection Diagram

Dual-In-Line Package



TL/F/6330–1

Order Number DM74AS873NT
See NS Package Number N24C

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Absolute Maximum Ratings

Supply Voltage	7V
Input Voltage	7V
Voltage Applied to Disabled Output	5.5V
Operating Free Air Temperature Range	0°C to +70°C
Storage Temperature Range	−65°C to +150°C
Typical θ_{JA}	
N Package	47.0°C/W

Note: This product meets application requirements of 500 temperature cycles from −65°C to +150°C.

Note: *The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.*

Recommended Operating Conditions

Symbol	Parameter		Min	Nom	Max	Units
V_{CC}	Supply Voltage		4.5	5	5.5	V
V_{IH}	High Level Input Voltage		2			V
V_{IL}	Low Level Input Voltage				0.8	V
I_{OH}	High Level Output Current				−15	mA
I_{OL}	Low Level Output Current				48	mA
t_W	Pulse Width	Enable High	5.5			ns
		$\overline{\text{Clear}}$ Low	3.5			
t_{SU}	Data Setup Time		2↓			ns
t_H	Data Hold Time		3↓			ns
T_A	Free Air Operating Temperature		0		70	°C

The (↓) arrow indicates the negative edge of the enable is used for reference.

Electrical Characteristics

over recommended operating free air temperature range. All typical values are measured at V_{CC} = 5V, T_A = 25°C.

Symbol	Parameter	Conditions		Min	Typ	Max	Units
V_{IK}	Input Clamp Voltage	V_{CC} = 4.5V, I_I = −18 mA				−1.2	V
V_{OH}	High Level Output Voltage	V_{CC} = 4.5V, V_{IL} = Max, I_{OH} = Max		2.4	3.3		V
		I_{OH} = −2 mA, V_{CC} = 4.5V to 5.5V		V_{CC} −2			V
V_{OL}	Low Level Output Voltage	V_{CC} = 4.5V, V_{IH} = 2V, I_{OL} = Max			0.35	0.5	V
I_I	Input Current at Max Input Voltage	V_{CC} = 5.5V, V_{IH} = 7V				0.1	mA
I_{IH}	High Level Input Current	V_{CC} = 5.5V, V_{IH} = 2.7V				20	μA
I_{IL}	Low Level Input Current	V_{CC} = 5.5V, V_{IL} = 0.4V				−0.5	mA
I_O (Note 1)	Output Drive Current	V_{CC} = 5.5V, V_O = 2.25V		−30		−112	mA
I_{OZH}	Off-State Output Current, High Level Voltage Applied	V_{CC} = 5.5V, V_{IH} = 2V, V_O = 2.7V				50	μA
I_{OZL}	Off-State Output Current, Low Level Voltage Applied	V_{CC} = 5.5V, V_{IH} = 2V, V_O = 0.4V				−50	μA
I_{CC}	Supply Current	V_{CC} = 5.5V Outputs Open	Outputs High		68	110	mA
			Outputs Low		67	109	mA
			Outputs Disabled		80	129	mA

Note 1: The output conditions have been chosen to produce a current that closely approximates one half of the true short circuit current, I_{OS}.

Switching Characteristics

over recommended operating free air temperature range (Note 1). All typical values are measured at V_{CC} = 5V, T_A = 25°C.

Symbol	Parameter	Conditions	From	To	Min	Max	Units
t_{PLH}	Propagation Delay Time Low to High Level Output	V_{CC} = 4.5V to 5.5V R_L = 500Ω C_L = 50 pF	Data	Any Q	3	6.5	ns
t_{PHL}	Propagation Delay Time High to Low Level Output		Data	Any Q	3	6	ns
t_{PLH}	Propagation Delay Time Low to High Level Output		Enable	Any Q	6	11.5	ns
t_{PHL}	Propagation Delay Time High to Low Level Output		Enable	Any Q	4	7.5	ns
t_{PZH}	Output Enable Time to High Level Output		$\overline{\text{Output}}$ Control	Any Q	2	6.5	ns
t_{PZL}	Output Enable Time to Low Level Output		$\overline{\text{Output}}$ Control	Any Q	4	9.5	ns
t_{PHZ}	Output Disable Time from High Level Output		$\overline{\text{Output}}$ Control	Any Q	2	6.5	ns
t_{PLZ}	Output Disable Time from Low Level Output		$\overline{\text{Output}}$ Control	Any Q	2	7.5	ns
t_{PHL}	Propagation Delay Time High to Low Level Output		$\overline{\text{Clear}}$	Any Q	3	8.5	ns

Note 1: See Section 5 for test waveforms and output load.

Function Table

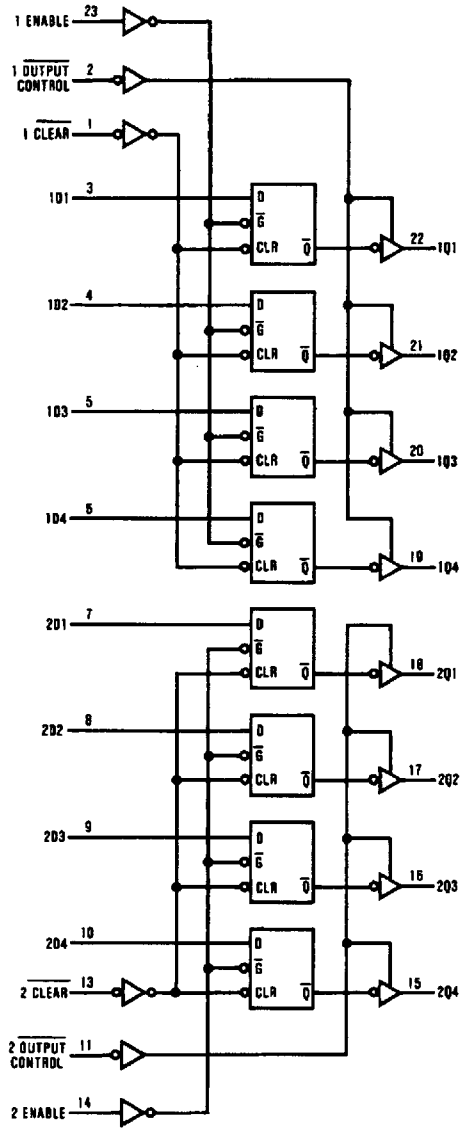
Inputs				Output
$\overline{\text{CLR}}$	D	EN	$\overline{\text{OC}}$	Q
X	X	X	H	Z
L	X	X	L	L
H	H	H	L	H
H	L	H	L	L
H	X	L	L	Q_0

L = Low State, H = High State, X = Don't Care

Z = High Impedance State

Q_0 = Previous Condition of Q

Logic Diagram



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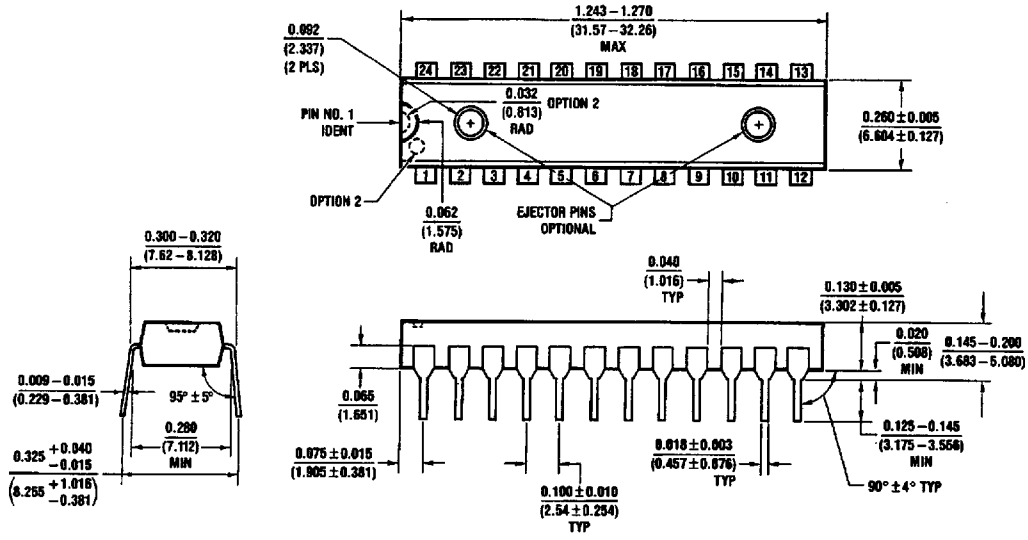
Physical Dimensions inches (millimeters)



Molded Dual-In-Line Package (N)
Order Number DM74AS873NT
NS Package Number N24C

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

National Semiconductor Corporation
1111 West Bardin Road
Arlington, TX 76017
Tel: 1(800) 272-9959
Fax: 1(800) 737-7018

http://www.national.com

National Semiconductor Europe
Fax: +49 (0) 180-530 85 86
Email: europe.support@nsc.com
Deutsch Tel: +49 (0) 180-530 85 85
English Tel: +49 (0) 180-532 78 32
Français Tel: +49 (0) 180-532 93 58
Italiano Tel: +49 (0) 180-534 16 80

National Semiconductor Hong Kong Ltd.
13th Floor, Straight Block,
Ocean Centre, 5 Canton Rd.
Tsimshatsui, Kowloon
Hong Kong
Tel: (852) 2737-1600
Fax: (852) 2736-9960

National Semiconductor Japan Ltd.
Tel: 81-043-299-2308
Fax: 81-043-299-2408